

## Excellent Integrated System Limited

Stocking Distributor

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[IXYS Corporation](#)

[DPG10I400PM](#)

For any questions, you can email us directly:

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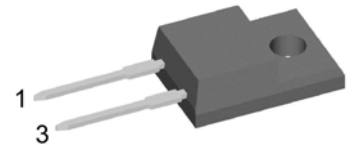
**HiPerFRED<sup>2</sup>**

$V_{RRM}$	=	400V
$I_{FAV}$	=	10A
$t_{rr}$	=	45ns

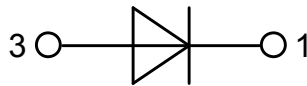
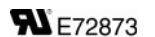
High Performance Fast Recovery Diode  
Low Loss and Soft Recovery  
Single Diode

Part number

**DPG10I400PM**



Backside: isolated



**Features / Advantages:**

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low  $I_{rm}$ -values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low  $I_{rm}$  reduces:
  - Power dissipation within the diode
  - Turn-on loss in the commutating switch

**Applications:**

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

**Package: TO-220FP**

- Isolation Voltage: 2500 V~
- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Soldering pins for PCB mounting
- Base plate: Plastic overmolded tab
- Reduced weight

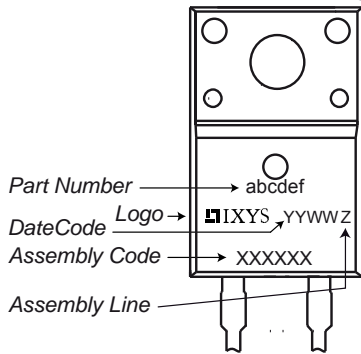
Fast Diode				Ratings		
Symbol	Definition	Conditions	min.	typ.	max.	Unit
$V_{RSM}$	max. non-repetitive reverse blocking voltage				400	V
$V_{RRM}$	max. repetitive reverse blocking voltage				400	V
$I_R$	reverse current, drain current	$V_R = 400\text{ V}$	$T_{VJ} = 25^\circ\text{C}$		1	$\mu\text{A}$
		$V_R = 400\text{ V}$	$T_{VJ} = 150^\circ\text{C}$		0.15	mA
$V_F$	forward voltage drop	$I_F = 10\text{ A}$	$T_{VJ} = 25^\circ\text{C}$		1.32	V
					1.51	V
		$I_F = 10\text{ A}$	$T_{VJ} = 150^\circ\text{C}$		1.03	V
					1.24	V
$I_{FAV}$	average forward current	$T_C = 125^\circ\text{C}$ rectangular $d = 0.5$	$T_{VJ} = 175^\circ\text{C}$		10	A
$V_{F0}$	threshold voltage	} for power loss calculation only	$T_{VJ} = 175^\circ\text{C}$		0.77	V
$r_F$	slope resistance				19.8	m $\Omega$
$R_{thJC}$	thermal resistance junction to case				4.4	K/W
$R_{thCH}$	thermal resistance case to heatsink			0.50		K/W
$P_{tot}$	total power dissipation		$T_C = 25^\circ\text{C}$		35	W
$I_{FSM}$	max. forward surge current	$t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}; V_R = 0\text{ V}$	$T_{VJ} = 45^\circ\text{C}$		150	A
$C_J$	junction capacitance	$V_R = 150\text{ V}$ $f = 1\text{ MHz}$	$T_{VJ} = 25^\circ\text{C}$		12	pF
$I_{RM}$	max. reverse recovery current	} $I_F = 10\text{ A}; V_R = 270\text{ V}$ $-di_F/dt = 200\text{ A}/\mu\text{s}$	$T_{VJ} = 25^\circ\text{C}$		4	A
			$T_{VJ} = 125^\circ\text{C}$		6	A
$t_{rr}$	reverse recovery time		$T_{VJ} = 25^\circ\text{C}$		45	ns
			$T_{VJ} = 125^\circ\text{C}$		65	ns



# DPG10I400PM

Package TO-220FP				Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit	
$I_{RMS}$	RMS current	per terminal			35	A	
$T_{VJ}$	virtual junction temperature		-55		175	°C	
$T_{op}$	operation temperature		-55		150	°C	
$T_{stg}$	storage temperature		-55		150	°C	
<b>Weight</b>					2	g	
$M_D$	mounting torque		0.4		0.6	Nm	
$F_C$	mounting force with clip		20		60	N	
$d_{Spp/App}$	creepage distance on surface   striking distance through air	terminal to terminal	3.2	2.7		mm	
$d_{Spb/Apb}$		terminal to backside	2.5	2.5		mm	
$V_{ISOL}$	isolation voltage	t = 1 second			2500	V	
		t = 1 minute	50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA		2080	V	

### Product Marking



### Part number

- D = Diode
- P = HiPerFRED
- G = extreme fast
- 10 = Current Rating [A]
- I = Single Diode
- 400 = Reverse Voltage [V]
- PM = TO-220ACFP (2)

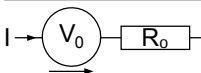
Ordering	Part Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DPG10I400PM	DPG10I400PM	Tube	50	503778

Similar Part	Package	Voltage class
DPG10I400PA	TO-220AC (2)	400

### Equivalent Circuits for Simulation

\* on die level

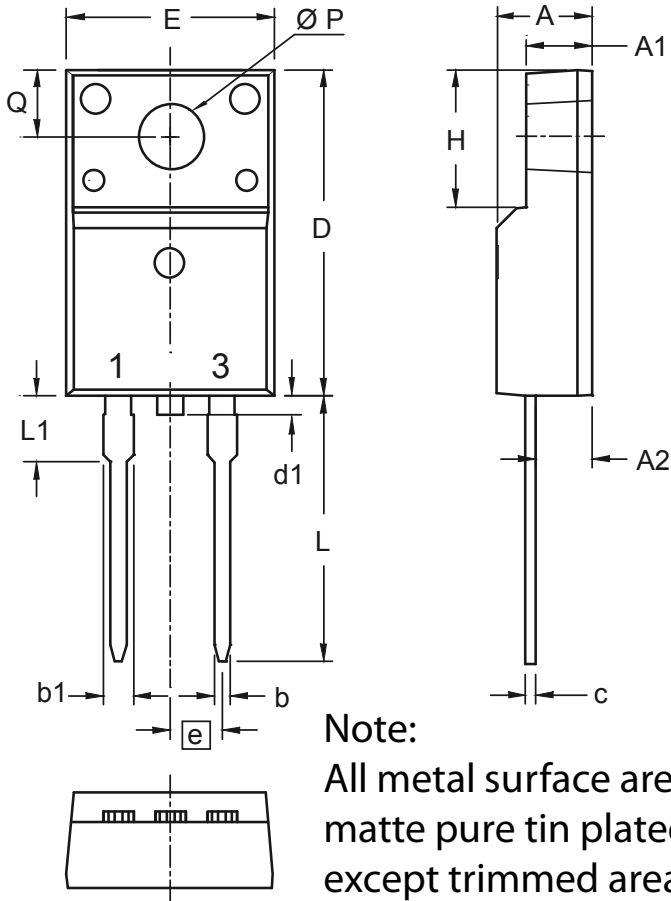
$T_{VJ} = 175\text{ °C}$



**Fast Diode**

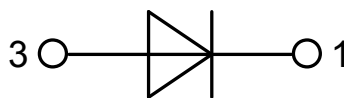
$V_{0\ max}$	threshold voltage	0.77	V
$R_{0\ max}$	slope resistance *	16.6	mΩ

Outlines TO-220FP



Note:  
All metal surface are  
matte pure tin plated  
except trimmed area.

Dim.	Millimeters		Inches	
	min	max	min	max
A	4.50	4.90	0.177	0.193
A1	2.34	2.74	0.092	0.108
A2	2.56	2.96	0.101	0.117
b	0.70	0.90	0.028	0.035
b1	1.27	1.47	0.050	0.058
c	0.45	0.60	0.018	0.024
D	15.67	16.07	0.617	0.633
d1	0	1.10	0	0.043
E	9.96	10.36	0.392	0.408
e	2.54 BSC		0.100 BSC	
H	6.48	6.88	0.255	0.271
L	12.68	13.28	0.499	0.523
L1	3.03	3.43	0.119	0.135
ØP	3.08	3.28	0.121	0.129
Q	3.20	3.40	0.126	0.134



**Fast Diode**

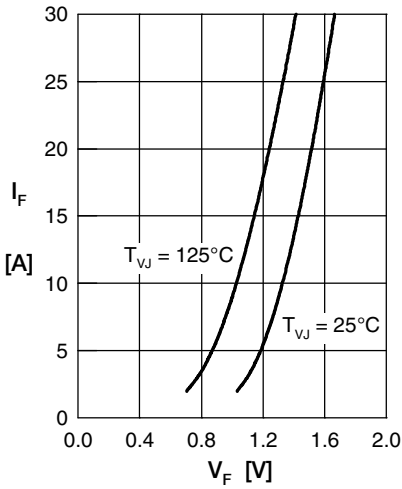


Fig. 1 Forward current  $I_F$  versus  $V_F$

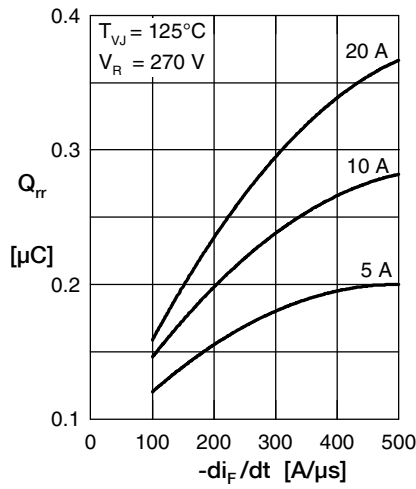


Fig. 2 Typ. reverse recov. charge  $Q_{rr}$  versus  $-di_F/dt$

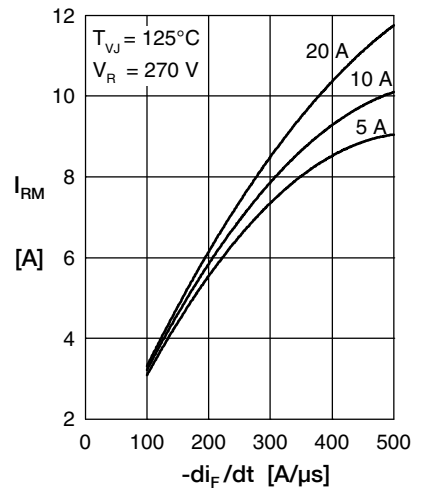


Fig. 3 Typ. reverse recov. current  $I_{RM}$  versus  $-di_F/dt$

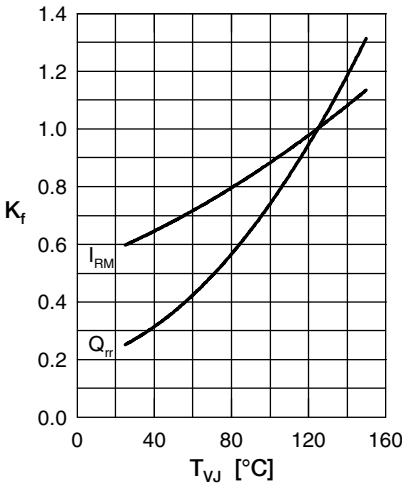


Fig. 4 Typ. dynamic parameters  $Q_{rr}$ ,  $I_{RM}$  versus  $T_{VJ}$

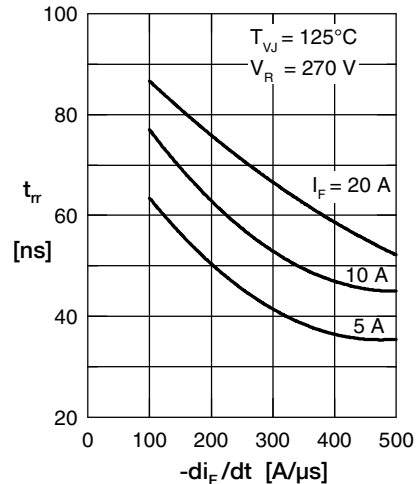


Fig. 5 Typ. reverse recov. time  $t_{rr}$  versus  $-di_F/dt$

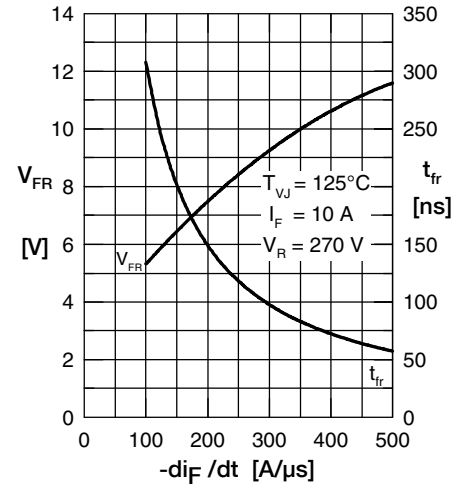


Fig. 6 Typ. forward recovery voltage  $V_{FR}$  and  $t_{fr}$  versus  $di_F/dt$

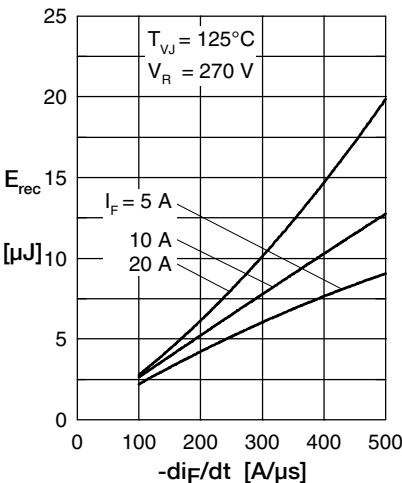


Fig. 7 Typ. recovery energy  $E_{rec}$  versus  $-di_F/dt$

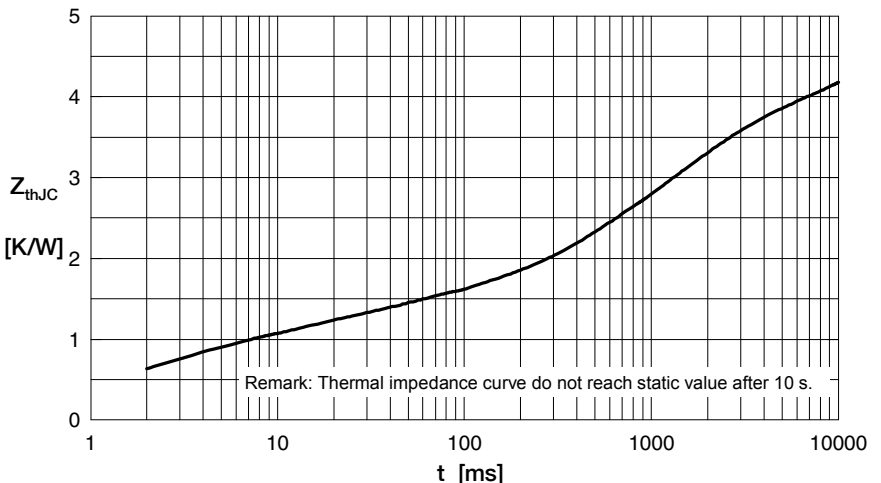


Fig. 8 Transient thermal resistance junction to case